2 SD 1867(M)	Rhm	Si-N-Darl+Di	=2SD1660(M): Pins = 14mm		9c				›2SD1660
2 SD 1868	Hit	Si-N	LF,Vid, 160/160V, 0,1A, 0,9W, 140MHz		7c(9mm)	TO-92L	(BF 759)[6]	13h	BF 391…393, 2SC3248, 2SC3467, ++
2 SD 1869	Hit	Si-N	=2SD1868: 200/200V		7c(9mm)	TO-92L	(BF 759)[6]	13h	BF 391…393, 2SC3467…3469, ++
2 SD 1870	Hit	Si-N	SMD, 30/25V, 1/2A, hi-hFE=1k…3k		39b	SOT-89			2SC3727, 2SD1950
2 SD 1871	Mit	Si-N	P, 40/20V, 2A, 10W		30j	TO-251/252	2SC4135	30j	2SD1078…79, 2SD1801…02, (BD 515,++)[4]
2 SD 1872	Mit	Si-N	P, 60/40V, 1,5A, 10W		30j	TO-251/252	2SC4135	30j	2SD1079, 2SD1221, 2SD1801…02, (BD 517+)[6]
2 SD 1873	Mit	Si-N	P, 110/100V, 0,8A, 10W		30j	TO-251/252	2SC4135	30j	2SD1074…75, 2SD1283…84, (BD 529)[6]
2 SD 1874	Mit	Si-N	P, 130/120V, 0,8A, 10W		30j	TO-251/252			2SC2983, 2SC4027, 2SD1080…82, 2SD1220,
2 SD 1875	Rhm	Si-N-Darl+Di	P, 50/50V, 1,5A, 10W, hFE=10000		14b	TO-126 Iso	(BD 679)[3]	14h	(BD 677, BD 777, 2N6038…39, 2SD1376,++)[3]
2 SD 1876	Say	Si-N+Di	TV-HA, 1500/800V, 3/12A, 50W, sat<5V(2A)		18c	TO-3P Iso	S 2055 AF	18c	BU 706DF, 2SD1553…54, 2SD1650, 2SD2089
2 SD 1877	Say	Si-N+Di	TV-HA, 1500/800V, 4/12A, 50W, sat<5V(2,5A)		18c	TO-3P Iso	S 2055 AF	18c	BU 706DF, 2SD1554…55, 2SD1651, 2SD2089
2 SD 1878	Say	Si-N+Di	TV-HA, 1500/800V, 5/20A, 60W, sat<5V(4A)		18c	TO-3P Iso	S 2055 AF	18c	BU 508DF, 2SD1555, 2SD2095, 2SD2125
2 SD 1879	Say	Si-N+Di	TV-HA, 1500/800V, 6/20A, 60W, sat<5V(5A)		18c	TO-5P Iso	S 2055 AF	18c	BU 508DF, 2SC4294, 2SD1556, 2SD2125
2 SD 1880	Say	Si-N+Di	TV-HA, 1500/800V, 8/30A, 70W, sat<5V(6A)		18c	TO-3P Iso	S 2055 AF	18c	BU 508DF,2SC3893A, 2SC4124, 2SC4531
2 SD 1881	Say	Si-N+Di	TV-HA, 1500/800V, 10/30A, 70W, sat<5V(8A)		18c	TO-3P Iso			BU 2520AF, 2SC4125, 2SC4531
2 SD 1882	Say	Si-N	=2SD1876: ohne/without Damper-Diode		18c	TO-3P Iso	S 2000 AF	18c	BU706F, 2SD1553, 2SD1653,(2SC3483…84,+)[3]
2 SD 1883	Say	Si-N	=2SD1877: ohne/without Damper-Diode		18c	TO-3P Iso	S 2000 AF	18c	BU706F, 2SD1544, 2SD1654,(2SC3484…86,+)[3]
2 SD 1884	Say	Si-N	=2SD1878: ohne/without Damper-Diode		18c	TO-3P Iso	BU 508 AF	16c	BU 508AF, 2SC4142, 2SD1545, 2SD1655, ++
2 SD 1885	Say	Si-N	=2SD1879: ohne/without Damper-Diode		18c	TO-3P Iso	BU 508 AF	16c	BU 508AF, 2SC4143, 2SD1546, 2SD1656[3]
2 SD 1886	Say	Si-N	=2SD1880: ohne/without Damper-Diode		18c	TO-3P Iso	2SD1577	16c	BU 508AF, 2SC3896,(BU 908, 2SC3687,++)[3]
2 SD 1887	Say	Si-N	=2SD1887: ohne/without Damper-Diode		18c	TO-3P Iso	2SC4924	18c	BU 2520AF, 2SC3897, (2SC3688)[3]
2 SD 1888	Rhm	Si-N-Darl+Di	P, 120/120V, 6/10A, 40W, 40MHz, hFE=2k…20k		17j	TO-220	2SD1756	17j	2SC2269, (BD 651, BDT 21, BDW 63D,++)[13]
2 SD 1889	Rhm	Si-N-Darl+Di	=2SD1888: Iso, 30W		17c	SOT-186			2SD1785, 2SD2025, 2SD1590, (BD649F)[13]
2 SD 1890	Mat	Si-N-Darl	P, 100/80V, 3/6A, 35W, 20MHz, hFE=5k…30k	{2SB1250	17c	SOT-186			-
2 SD 1891	Mat	Si-N-Darl	P, 110/90V, 4/7A, 40W, 20MHz, hFE=5k…30k	{2SB1251	17c	SOT-186			-
2 SD 1892	Mat	Si-N-Darl	P, 120/110V, 5/8A, 45W, 20MHz, hFE=5k…30k	{2SB1252	17c	SOT-186			-
2 SD 1893	Mat	Si-N-Darl	P,130/110V, 6/10A, 50W, 20MHz, hFE=5k…30k	{2SB1253	16c	(TOP-3F)			-
2 SD 1894	Mat	Si-N-Darl	P,160/140V, 7/12A, 70W, 20MHz, hFE=5k…30k	{2SB1254	16c	(TOP-3F)			-
2 SD 1895	Mat	Si-N-Darl	P,160/140V, 8/15A, 100W, 20MHz, hFE=5…30k	{2SB1255	16c	(TOP-3F)			-
2 SD 1896	Rhm	Si-N	P, 100/100V, 5/10A, 40W, 8MHz		17j	TO-220	BD 243 C	17j	BD 243C, BD 539C, BD 543C, BD 953, ++
2 SD 1897	Rhm	Si-N	=2SD1896: Iso, 30W		17c	SOT-186	2SD1411	17c	BD 953F, 2SC3691, 2SD1407, 2SD1940, ++
2 SD 1898	Rhm	Si-N	SMD, Uni, 100/80V, 1A, 100MHz		39b	SOT-89			BCX 56, 2SD1005, 2SD1386, 2SD1418…19
2 SD 1899(Z)	Nec	Si-N	P,60/60V, 3/5A, 10W, 120MHz, <0,5/2,5µs, Z: TO-252		30j	TO-251/252	2SC3303	30j	2SC3386, 2SD1221, 2SD1802, 2SD1815…16++
2 SD 1900	Hit	Si-N-Darl	P, 60/60V, 4A, 25W, hFE=5000		15c		(BD 901)[3]	17j	2SD1790, 2SD1796, 2SD1825, 2SD1987, ++
2 SD 1901	Hit	Si-N-Darl	P, 60/60V, 8A, 25W, hFE=5000		15c		(BD 901)[3]	17j	2SD1416…17, 2SD1793, 2SD1826…27, ++
2 SD 1902	Say	Si-N	LF P, 60/60V, 3/8A, 30W, 40MHz	{2SB1266	30c	(TO-220MF)	(BD 243 C)[6]	17j	2SD1251…52,(BD 241A, BD 535, BD 539A,+)[6]
2 SD 1903	Say	Si-N	S P, 60/30V, 8/15A, 30W, 120MHz, lo-sat<0,4V(3A) 100/530ns	{2SB1267	30c	(TO-220MF)			-
2 SD 1904	Say	Si-N	S P, 60/50V, 5/9A, 30W, 30MHz, lo-sat<0,4V(3A) 100/1600ns	{2SB1268	30c	(TO-220MF)			2SD1906, 2SD2198, 2SD2200
2 SD 1905	Say	Si-N	S P, 60/50V, 7/12A, 40W, 10MHz, lo-sat<0,4V(4A) 100/1200ns	{2SB1269	30c	(TO-220MF)			2SD1907, 2SD2199, 2SD2201
2 SD 1906	Say	Si-N	S P, 90/80V, 5/9A, 30W, 20MHz, lo-sat<0,4V(3A) 100/1600ns	{2SB1270	30c	(TO-220MF)			2SD1907, 2SD2200…01
2 SD 1907	Say	Si-N	S P, 90/80V, 7/12A, 40W, 20MHz, lo-sat<0,4V(4A) 100/2000ns	{2SB1271	30c	(TO-220MF)			2SD2201
2 SD 1908	Say	Si-N	TV-HA, 330/150V, 7A, 50W, 40MHz, sat<1V(5A)		30c	(TO-220MF)	(BU 406)[6]	17j	(BU 406…408, 2SC3173, 2SD884…885,++)[6]
2 SD 1909	Mat	Si-N-Darl	P, 500/300V, 6/10A, 45W, 20MHz, hFE>500, 1/15µs		17c	SOT-186	2SD1409	17c	2SD1409
2 SD 1910	Hit	Si-N+Di	TV-HA, 1500/600V, 3A, 40W, sat<5V(2,5A)		≈18c	(TO-3PFM)	S 2055 AF	18c	2SD1544, 2SD1653, BU 706DF, (2SC3479,++)[3]
2 SD 1910 FI	Tho	Si-N+Di	=2SD1910:		18c	TO-3P Iso	S 2055 AF	18c	2SD1544, 2SD1653, BU 706DF, (2SC3479,++)[3]
2 SD 1911	Hit	Si-N+Di	TV-HA, 1500/600V, 5A, 50W, sat<5V(4,5A)		≈18c	(TO-3PFM)	BU 508 DF	16c	BU 508DF, 2SC4293, 2SC4122, 2SD1651, ++
2 SD 1912	Say	Si-N	LF P, 60/60V, 3/8A, 30W, 100MHz	{2SB1273	17j	TO-220	(BD 243 C)[6]	17j	2SC3252, (BD 241A, BD 535, BD 539A,++)[8]
2 SD 1913	Say	Si-N	=2SD1912: Iso, 20W	{2SB1274	17c	TO-220 Iso	2SC3299	17c	2SC3299, 2SC3691, 2SC3746
2 SD 1914	Say	Si-N-Darl+Di	P Drv, 100/80V, 2/4A, 10W, hFE=2k…30k		≈14h	≈SOT-82			(2SD1376, 2SD1953)
2 SD 1915	Mat	Si-N	50/20V, hi-Ueb=25V, 0,3/0,5A, 0,3W, 80MHz, hi-hFE=500…2500		40c		(2SC3225)	7c(9mm)	2SC3615, (2SC3247, 2SD1582)
2 SD 1916	Tos	Si-N-Darl+Di	Uni, 50/50V, 2A, 1W, hFE=5000, <1,2/13,8µs		9c		2SD1153	7c(9mm)	2SD1153, 2SD1809, 2SD1866, 2SD1853, ++
2 SD 1917	Mat	Si-N-Darl	int. Z-Di(C→B, 60V), 60/60V, 1A, B=20000		14b	TO-126			-
2 SD 1918(F5)	Rhm	Si-N	P,160/160V, 1,5/3A, 10W, 80MHz, F5: TO-252	{2SB1275	30j	TO-251/252			2SC2983, 2SC4027, 2SD1080…82, 2SD2122
2 SD 1919	Rhm	Si-N	=2SD1055: Pins = 14mm	{2SB1277	9c		›2SD1055		›2SD1055
2 SD 1920	Rhm	Si-N	=2SD1469: Pins = 14mm		9c		›2SD1469		›2SD1469
2 SD 1921	Rhm	Si-N	=2SD1787: Pins = 14mm		9c		›2SD1787		›2SD1787
2 SD 1922	Hit	Si-N+Di	int. Z-Di(C→B), 25/25V, 0,8/1,5A, 0,9W hFE=250…1200, lo-sat<0,3V(0,8A)		7c(9mm)	TO-92L			-
2 SD 1923	Hit	Si-N-Darl+Di	P, 80/80V, 4A, 25W, hFE=5000		15c		2SD1415	17c	2SD1589, 2SD1928, 2SD1933, 2SD2014
2 SD 1924	Hit	Si-N-Darl+Di	P, 80/80V, 8A, 25W, hFE=5000		15c		2SD1415	17c	2SC4062, 2SD1415…16, 2SD1793
2 SD 1925	Hit	Si-N-Darl+Di	P, 120/120V, 3A, 25W, hFE=5000		15c				2SD1785, 2SD2015, (BDW 53D, BDW 63D,++)[3]
2 SD 1926	Hit	Si-N-Darl	P, 200/200V, 10A, 30W, hFE=5000		15c				2SD1794, (2SD1756)[3]
2 SD 1927	Hit	Si-N-Darl+Di	P, 120/120V, 6A, 25W, hFE=5000		15c				2SD1590, (BD 651, BDW 73D, BDX 53D,++)[3]
2 SD 1928	Nec	Si-N-Darl+Di	S P, 100/100V, ±8/16A, 25W, hFE=2k…20k, 0,4/3µs		17c	SOT-186	2SD1415	17c	BD 647F, 2SC4062, 2SD1415, 2SD1791
2 SD 1929	Rhm	Si-N-Darl+Di	int. Z-Di(C→B), 60/60±10V, 2A, 1,2W, hFE=1k…10k		7c(9mm)	TO-92L	2SD1153	7c(9mm)	2SD1854, 2SD1931, 2SD1981
2 SD 1930	Rhm	Si-N-Darl	Uni, 100/100V, 2A, 1,2W, hFE=1k…10k		7c(9mm)	TO-92L			2SD1978, 2SD1981, 2SD2206
2 SD 1931	Rhm	Si-N-Darl+Di	int. Z-Di(C→B), 60/60±10V, 1,5/3A, 0,9W, 80MHz hFE=1k…30k		7c(9mm)	TO-92L			-
2 SD 1932	Rhm	Si-N-Darl+Di	P, 80/80V, 4/6A, 35W, 40MHz, hFE=1k…10k	{2SB1341	17j	TO-220	BD 901	17j	BD 717, BDW 32B, BDW 53B, 2SD1147, ++
2 SD 1933	Rhm	Si-N-Darl+Di	=2SD1932: Iso, 30W	{2SB1342	17c	SOT-186	2SD1415	17c	BD 647F, 2SD1589, 2SD1788, 2SD1928, ++
2 SD 1934	Mat	Si-N	=2SD965: 1W		7c(9mm)	TO-92L	2SD2179	9c	2SD966, 2SD1244, 2SD2249, 2SD1961
2 SD 1935	Say	Si-N	=2SD1936: SMD	{2SB1295	35a	SOT-23			2SC3265
2 SD 1936	Say	Si-N	LF, 15/15V, 0,8/3A, 0,3W, 200MHz, sat<0,2V(0,4A)		41c	(SPA)	2SD1207	7c	2SC3225, 2SD1207, 2SD1835
2 SD 1937	Mat	Si-N	=2SD1211:	{2SB1297	7c(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SC3228, 2SD667(A), 2SD1616A,++
2 SD 1938	Mat	Si-N	=2SD1915: SMD		35a	SOT-23			-
2 SD 1939	Nec	Si-N-Darl+Di	S, 150/60V, ±1,5/3A, 0,75W, hFE=2k…30k, 0,5/2µs		7c	TO-92			2SD1579, 2SD1659
2 SD 1940	Say	Si-N	P, 100/85V, 6/10A, 25W, 15MHz, 0,28/4,1µs		17c	TO-220 Iso	2SD1411	17c	2SC3692, 2SD1411, 2SD1588
2 SD 1941	Hit	Si-N	TV-HA, 1500/650V, 6A, 50W, sat<5V(5A)		≈18c	(TO-3PFM)	BU 508 AF	16c	BU508AF, 2SC4143, 2SD1545…47, 2SD1652,+
2 SD 1942	Rhm	Si-N	LF, 40/32V, 2A, 1,2W		7c(9mm)	TO-92L	2SD1207	7c(9mm)	2SC3328, 2SC4145, 2SD1146, 2SD1207, ++
2 SD 1943	Rhm	Si-N	80/60V, 3/6A, 40W, 50MHz, hi-hFE=400…2000		17j	TO-220	(2SD1273)	17c	2SD2085, (2SD1157, 2SC1983)[8]
2 SD 1944	Rhm	Si-N	=2SD1943: Iso, 30W		17c	SOT-186	2SD1273	17c	2SD1273, 2SD2092, 2SD2156, 2SD2375,++
2 SD 1945	Hit	Si-N	P, 1000/1000V, 0,5A, 20W		30j	TO-251/252			(BUX 87)[4]
2 SD 1946	Hit	Si-N	SMD, 15/10V, 1/2A, hi-hFE=400…2000		39b	SOT-89			2SC4390, 2SD1870
2 SD 1947	Tos	Si-N+Di	100/100V, 10/15A, 70MHz, hi-hFE=500…1500, 0,5/7µs, lo-sat<0,3V(5A)		17c	SOT-186			2SC4024
2 SD 1948	Tos	Si-N+Di	int. Z-Di(C→B, 60V), 60/60V, 5/8A, 110MHz, hi-hFE=500…1500, 0,1/2,5µs, lo-sat<0,3V(3A)		17c	SOT-186			2SD2075…2076